阅读申明

- 1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任何异议请及时告之,我们将妥善解决。
- 2.本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
- 3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。
- 4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

- 1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
- 2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
- 3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
- 4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".



Panasonic

ideas for life

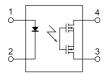
Lower output capacitance and on resistance. (C × R20) High speed switching. (Turn on time: 0.04ms, Turn off time: 0.06ms).

RF PhotoMOS (AQY221N1S)

4.4

4.3 .169 .173 12.1 .083

mm inch



FEATURES

1. Low output capacitance between output terminals and low ON-resistance

Output capacitance(C): 2.0pF (typ.) ON resistance(R): 9.8Ω (typ.)

2. High speed switching

Turn on time: 40ms Turn off time: 60ms

3. SO package 4-pin type in super miniature design

Size: (W)4.3 \times (L)4.4 \times (H)2.1 mm (W).169 \times (L).173 \times (H).083 inch

4. Low-level off state leakage current The SSR has an off state leakage current of several milliamperes, where as this PhotoMOS relay has typ. 10pA (typical) even with the rated load voltage

5. Controls low-level analog signals

6. Low thermal electromotive force (Approx. 1 mV)

TYPICAL APPLICATIONS

Measuring and testing equipment

1. Testing equipment for semiconductor performance

IC tester, Liquid crystal driver tester, semiconductor performance tester

2. Board tester

Bear board tester, In-circuit tester, function tester

3. Medical equipment

Ultrasonic wave diagnostic machine

4. Multi-point recorder (warping, thermo couple)

TYPES

Туре	Output rating*		Tape and reel	packing style	Packing quantity	
	Load voltage	Load current	Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel
AC/DC type	40V	120mA	AQY221N1SX	AQY221N1SZ	1,000 pcs	1,000 pcs

^{*} Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube.

(Part No. suf x "X" or "Z" is not needed when ordering; Tube: 100 pcs.; Case: 2,000 pcs.)

(2) For space reasons, the initial letters of the product number "AQY and S", the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221N1S	Remarks	
Input	LED forward current		lF	50mA	
	LED reverse	LED reverse voltage		5V	
	Peak forward current		I _{FP}	1A	f=100 Hz, Duty factor=0.1%
	Power dissipation		Pin	75mW	
Output	Load voltage (peak AC)		VL	40V	
	Continuous	Continuous load current		0.12A	Peak AC,DC
	Peak load c	Peak load current		0.30A	100 ms (1 shot), V∟= DC
	Power dissipation		Pout	300mW	
Total power dissipation		Рт	350mW		
I/O isolation voltage		Viso	1,500V AC		
Temperature limits Operating Storage		Topr	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
		Storage	Tstg	-40°C to +100°C -40°F to +212°F	

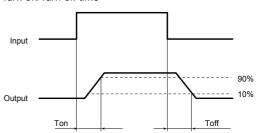
RF PhotoMOS (AQY221N1S)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item	ı		Symbol	AQY221N1S	Condition	
Input	LED operate current		Typical	IFon	0.9mA	I∟=100 mA	
			Maximum	IFon	3.0mA	IL- TOO TIIA	
	LED turn off current		Minimum	Foff	0.4mA	IL=100 mA	
			Typical		0.85mA		
	LED dropout voltage		Typical	VF	1.25V (1.14V at I⊧=5mA)	I _F =50mA	
			Maximum		1.5V	Amuc=al	
Output	On resistance #		Typical	Ron	9.8Ω	I⊧=5mA I∟=100 mA Within 1 s on time	
			Maximum		12.5Ω		
	Output capacitance #		Typical	Cout	2.2pF	I _F =0mA V _B =0V	
			Maximum		2.5pF	f=1 MHz	
	Off state leakage current		Typical	Leak	0.01nA	I⊧=0mA V∟=Max.	
			Maximum		10nA		
Transfer characteristics	Switching speed	Turn on time*	Typical	Ton	0.04ms	I _F =5mA V _L =10V R _L =100Ω	
			Maximum		0.5ms		
		Turn off time*	Typical	Toff	0.06ms	I _F =5mA V _L =10V R _L =100Ω	
			Maximum		0.2ms		
	I/O capacitance		Typical	Ciso	0.8pF	f=1MHz V _B =0V	
			Maximum		1.5pF		
	Initial I/O isolation resistance		Minimum	Riso	1,000ΜΩ	500V DC	

Note: Recommendable LED forward current $I_F = 5mA$.



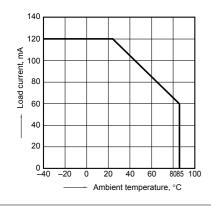


Other types of products than the Cout (typ. 2.0pF) and Ron (A connection typ. 9.8 ohm) combinations carried in this catalog are also available. (There is a trade-off between Ron and Cout both cannot be reduced at the same time.) For more information, please contact our sales of ce in your area.

REFERENCE DATA

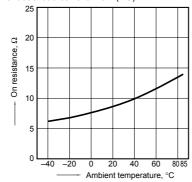
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



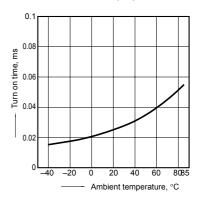
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

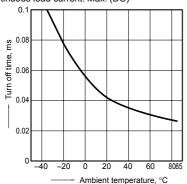
LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



RF PhotoMOS (AQY221N1S)

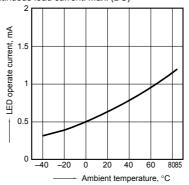
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



5. LED operate current vs. ambient temperature characteristics Load voltage: Max. (DC);

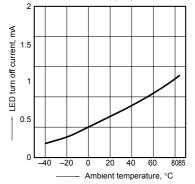
Continuous load current: Max. (DC)



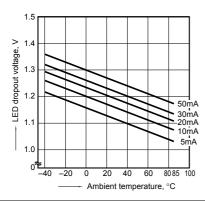
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);

Continuous load current: Max. (DC)

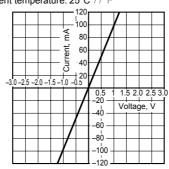


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



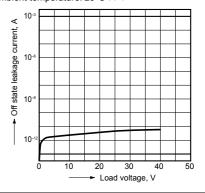
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



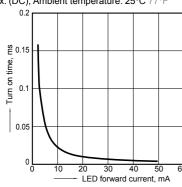
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



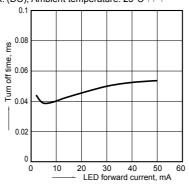
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



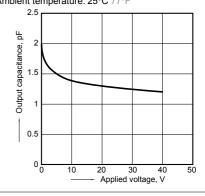
11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



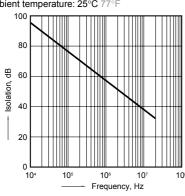
12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4 Frequency: 1 MHz, 30m Vrms; Ambient temperature: 25°C 77°F



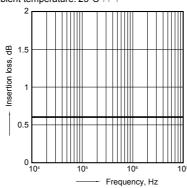
13. Isolation vs. frequency characteristics (50 $\!\Omega$ impedance)

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



14. Insertion loss vs. frequency characteristics (50 Ω impedance)

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F

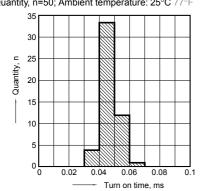


15. On resistance distribution

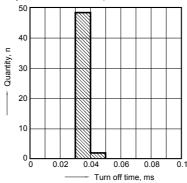
Measured portion: between terminals 3 and 4 Continuous load current: 120mA(DC) Quantity, n=50; Ambient temperature: 25°C 77°F

RF PhotoMOS (AQY221N1S)

16. Turn on time distribution
Load voltage: 40V(DC)
Continuous load current: 120mA(DC)
Quantity, n=50; Ambient temperature: 25°C 77°F



17. Turn off time distribution
Load voltage: 40V(DC)
Continuous load current: 120mA(DC)
Quantity, n=50; Ambient temperature: 25°C 77°F



18. LED operate current distribution Load voltage: 40V(DC) Continuous load current: 120mA(DC) Quantity, n=50; Ambient temperature: 25°C 77°F

